

QuickSwitch® Pulsed Laser Diode QS-905 Series

Description

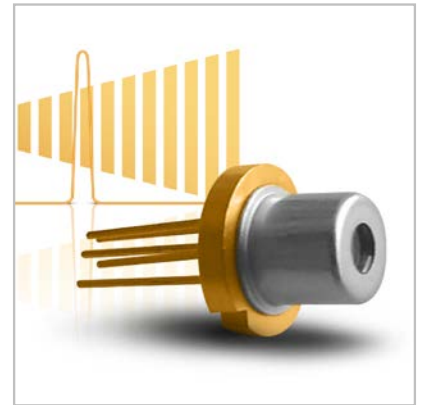
Ultra-compact module containing a high current switch, charge storage capacitor and pulsed laser diode inside a small hermetic package. The high current loop is all internal to the package which provides EMI shielding when the switch is active. The package has an independent ground pin from the signal and supply returns.

Features

- Hermetic TO-56 package (5 pins)
- 905 nm triple junction laser diode, 3 mil & 9 mil stripe
- Pulse width of 2.5 ns typical, enables high resolution ranging applications
- Low voltage charge storage: 1.5 V to 80 V DC
- Pulse frequency: up to 200 KHz
- Evaluation board available
- Available for mass production

Applications

- High resolution range finding for consumers
- Laser scanning / LIDAR
- Drones
- Optical trigger
- Automotive
- Robotics
- Military
- Industrial



Optical Characteristics at $t_{RT} = 21^\circ\text{C}$

	Min	Typ	Max	Units
λ of peak radiant intensity	895	905	915	nm
Spectral FWHM		8		nm
$\delta\lambda/\delta t^\circ$		0.27		nm/ $^\circ\text{C}$
Divergence FWHM				
Parallel to junction plane		12		Degrees
⊥ Perpendicular to junction plane		20		Degrees
Emitting Area				μm
1S3J09		10 x 225		
1S3J03		10 x 75		

Typical Product Characteristics

Conditions are $t_{RT} = 21^\circ\text{C}$, P_w (trig) = 40 ns, Rep. Rate = 10 KHz;

Parameter	QS905D1S3J09U		QS905D1S3J03U		Units
	Min	Max	Min	Max	
HV for P_o	15	80	15	80	V
P_o at HV (Typ.)	15	89	12	71	W
Pulse energy (Typ.)	30	220	26	185	nJ
Pulse width (Typ.)	2.0	2.5	2.2	2.6	ns

Absolute Maximum Ratings

Maximum Ratings Parameter	QS905D1S3J09U/03U	Units
HV	80	V
P_o at HV Max	89 / 71	W
V trig Max	6	V
Temperature		$^\circ\text{C}$
- Storage	- 55 to 100	$^\circ\text{C}$
- Operating	- 45 to 60	$^\circ\text{C}$

Figure 1: Performance Plot

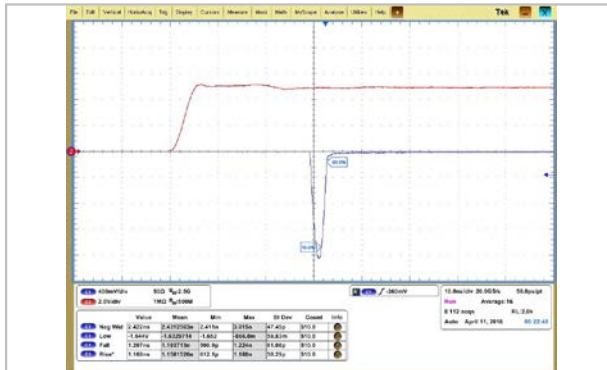


Figure 2: Instantaneous Peak Power vs Pulse Frequency

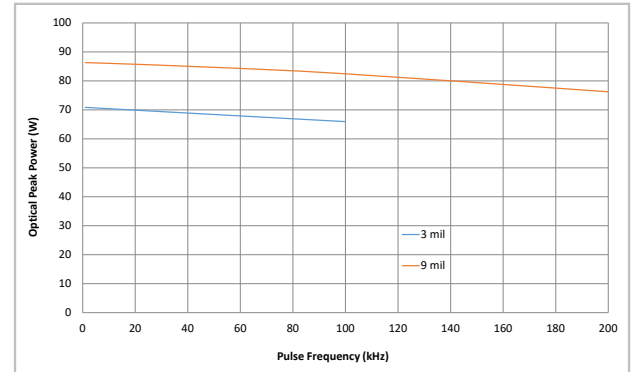


Figure 3: Pulse width, FWHM (ns) vs HV (High Voltage)

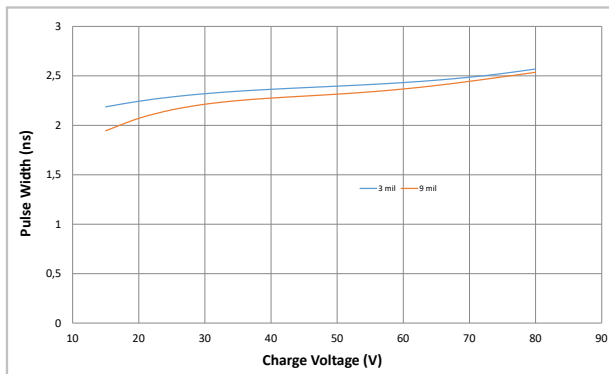


Figure 4: Optical Peak Power vs Charging Voltage (HV)

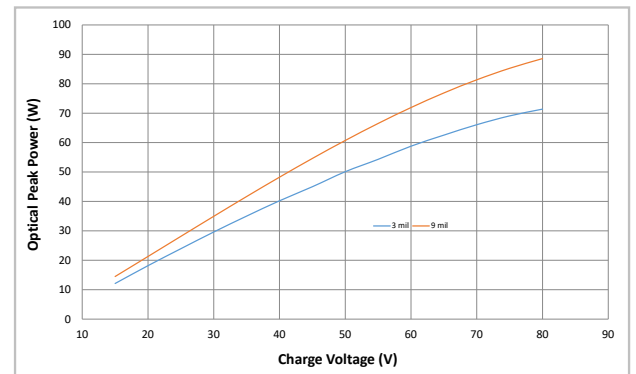
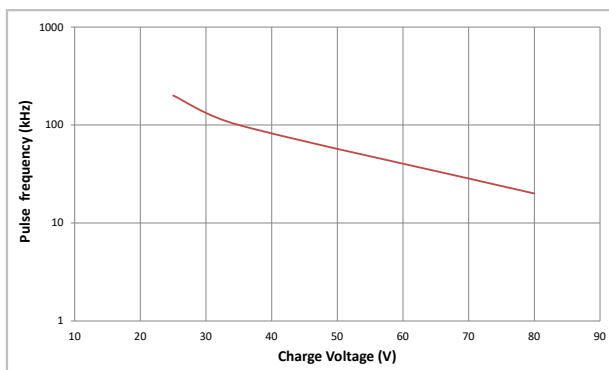
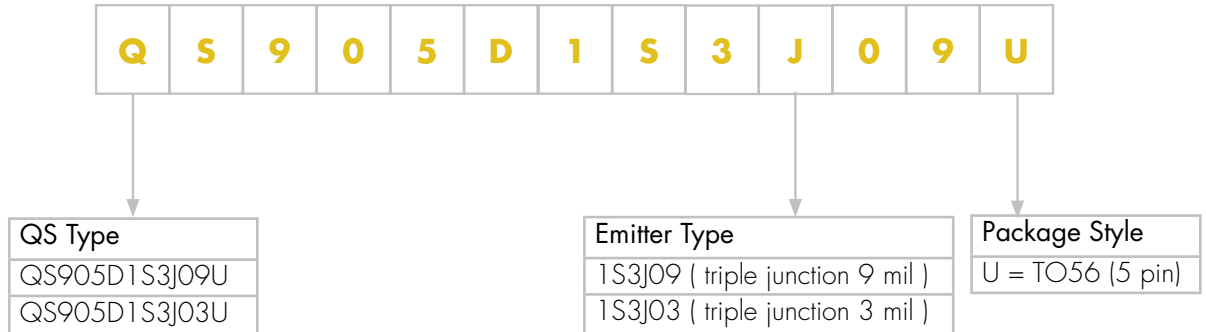


Figure 5: Pulse frequency vs HV (High Voltage) for devices without Heat Sink

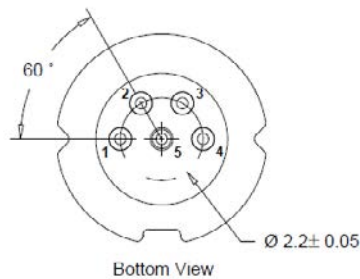


Product Number Designations



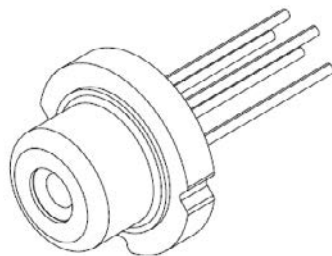
Package Drawing

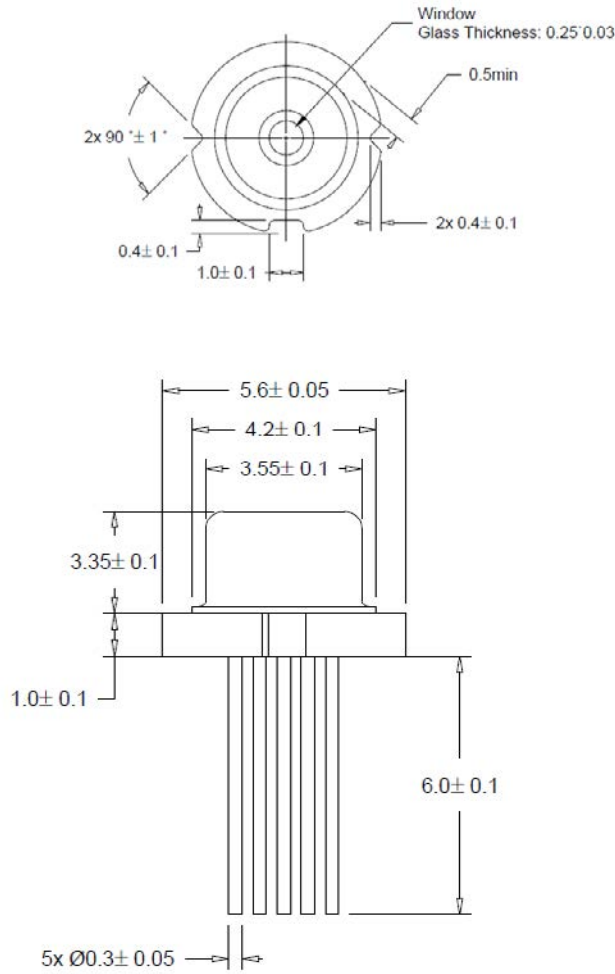
Package QS



Pin Out

- 1: Gate
- 2: N.C. (GND)
- 3: HV (High Voltage)
- 4: GND (Ground)
- 5: Case

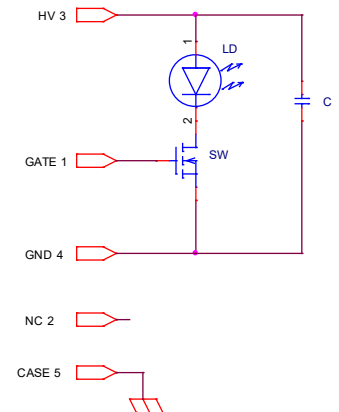




PIN Configuration (NEW PINOUT)

Pin	Function	Comment
1	GATE	0V OFF, ON 5V min/5.4 V Nominal Tr to be < 2 ns to meet FWHM
2	N.C.	Unused, GND recommended.
3	HV	15 V / 80 DC
4	GND	GND (HV and GATE return)
5	CASE	Connect to GND for case to acts as a shield.

Electrical Schematic



Evaluation Board & Driver: QS-EVAL DRIVER 2

25 mm x 51 mm evaluation board and QuickSwitch® driver is available upon request.

Product Changes

LASER COMPONENTS reserves the right to make change to the product information contained herein without notice. No liability is assumed as a result of their use or application.

Ordering Information

Products can be ordered directly from LASER COMPONENTS or its representatives. For a complete listing of representatives, visit our website at www.lasercomponents.com